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**PATENT APPLICATION**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Attn: OIPE

Akinori KOUKITSU et al.

Group Art Unit: 1722

Application No.: 10/509,177

Docket No.: 121213

Filed: September 27, 2004

For: VAPOR PHASE GROWTH METHOD FOR Al-CONTAINING III-V GROUP  
COMPOUND SEMICONDUCTOR, AND METHOD AND DEVICE FOR  
PRODUCING Al-CONTAINING III-V GROUP COMPOUND SEMICONDUCTOR

**REQUEST FOR CORRECTION OF PALM RECORDS**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Attached is a photocopy of the original filing receipt on which errors have been corrected in red. These errors are being brought to the attention of the Patent and Trademark Office so that it may correct its records. A Supplemental Application Data Sheet is attached.

Respectfully submitted,

James A. Oliff  
Registration No. 27,075

Randi B. Isaacs  
Registration No. 56,046

JAO:RBI/emt

Date: September 5, 2006

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<p>DEPOSIT ACCOUNT USE AUTHORIZATION Please grant any extension necessary for entry; Charge any fee due to our Deposit Account No. 15-0461</p>
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UNITED STATES PATENT AND TRADEMARK OFFICE

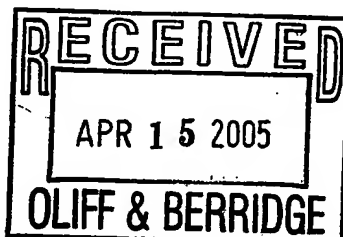


UNITED STATES DEPARTMENT OF COMMERCE  
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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/509,177	09/27/2004	1765	1092	121213	5	17	5

CONFIRMATION NO. 5228

25944  
 OLIFF & BERRIDGE, PLC  
 P.O. BOX 19928  
 ALEXANDRIA, VA 22320



FILING RECEIPT



\*OC000000015705278\*

Date Mailed: 04/11/2005

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

**Applicant(s)**

Akinori Koukitsu, Koganei-shi, JAPAN;  
 Yoshinao Kumagai, Koganei-shi, JAPAN;  
 Tomohiro Marui, Koganei-shi, JAPAN;

**Assignment For Published Patent Application**

TOKYO UNIVERSITY AGRICULTURE AND TECHNOLOGY TLO CO, Koganei-shi, JAPAN

**Power of Attorney:** The patent practitioners associated with Customer Number 25944.

**Domestic Priority data as claimed by applicant**

This application is a 371 of PCT/JP03/04408 04/07/2003

**Foreign Applications**

JAPAN 2002-106102 04/09/2002

**Projected Publication Date:** 07/21/2005

**Non-Publication Request:** No

**Early Publication Request:** No

**Title**

\* See next page for correction

A1

Vapor phase growth method for ~~al~~-containing III-V group compound semiconductor, and method and device for producing ~~al~~-containing III-V group compound semiconductor

A1

Preliminary Class

117

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Title 37, Code of Federal Regulations, 5.11 & 5.15**

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ATTORNEYS AT LAW

**Supplemental Application Data Sheet**

**Application Information**

Application Type::	National Phase
Subject Matter::	Utility
CD-ROM or CD-R:	None
Title::	VAPOR PHASE GROWTH METHOD FOR <u>A1Al</u> -CONTAINING III-V GROUP COMPOUND SEMICONDUCTOR, AND METHOD AND DEVICE FOR PRODUCING <u>A1Al</u> -CONTAINING III-V GROUP COMPOUND SEMICONDUCTOR
Attorney Docket Number::	121213
Suggested Drawing Figure::	
Total Drawing Sheets::	5
Small Entity::	No

**Applicant Information**

Applicant Authority type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
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Country of Residence::	JAPAN

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Applicant Authority type::	Inventor
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Applicant Authority type::	Inventor
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Family Name::	MARUI
City of Residence::	Koganei-shi
Country of Residence::	JAPAN

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### Correspondence Information

Correspondence Customer Number:: 25944

<b>Domestic Priority Information</b>			
Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application is a	National Stage of	PCT/JP03/04408	4/7/2003
<b>Foreign Priority Information</b>			
Country::	Application Number::	Filing Date::	Priority Claimed::
JAPAN	2002-106102	4/9/2002	Yes
<b>Assignee Information</b>			
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Country of mailing address::	JAPAN		
Postal or Zip Code of mailing address::	184-8588		